

# IntelliMAX™ Advanced Load Products

## FPF1007 - FPF1009

### General Description

The FPF1007/8/9 are low  $R_{DS(on)}$  P-Channel MOSFET load switches offered in a selection of 10  $\mu$ s, 80  $\mu$ s, and 1 ms slew rate turn-on options for transient / in-rush current control. To support trends in mobile application requirements, the minimum operating input voltage has been reduced down to 1.2 V, the input current leakage has been minimized to extend battery life, and the ESD-protection has been designed to withstand a minimum of 8 kV (HBM) and 2 kV (CDM).

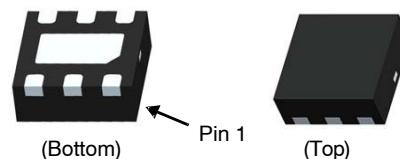
The switch is controlled by an active-high logic input (ON pin), allowing direct interface with a low-voltage control signal. An internal ON pin pull-down resistor protects against unintentional device turn-on in the initial state. An on-chip pull-down resistor on the output is enabled when the switch is turned-off and provides quick, robust discharge of the output load.

### Features

- 1.2 to 5.5 V Input Voltage Range
- Typical  $R_{DS(on)} = 30 \text{ m}\Omega$  at  $V_{IN} = 5.5 \text{ V}$
- Typical  $R_{DS(on)} = 40 \text{ m}\Omega$  at  $V_{IN} = 3.3 \text{ V}$
- Fixed Three Different Turn-on Rise Time 10  $\mu$ s / 80  $\mu$ s / 1 ms
- Low  $< 10 \text{ }\mu\text{A}$  at  $V_{IN} = 3.3 \text{ V}$  Quiescent Current
- Internal ON Pin Pull Down
- Output Discharge Function
- ESD Protection above 8000 V HBM and 2000 V CDM
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### Applications

- PDAs
- Cell Phones
- GPS Devices
- MP3 Players
- Digital Cameras
- Peripheral Ports
- Hot-Swap Supplies
- Notebook Computers



WDFN6 2x2, 0.65P  
CASE 511CY

### MARKING DIAGRAM

&E&E&Y  
&Oxxx&C  
&.&O&E&V

&E	= Designates Space
&Y	= Binary Calendar Year Coding Scheme
&O	= Plant Code identifier
xxx	= Device Specific Code
&C	= Single digit Die Run Code
&.	= Pin One Dot
&V	= Eight-Week Binary Datecoding Scheme

### ORDERING INFORMATION

See detailed ordering and shipping information on page 10 of this data sheet.

# FPF1007 – FPF1009

## Typical Application Circuit

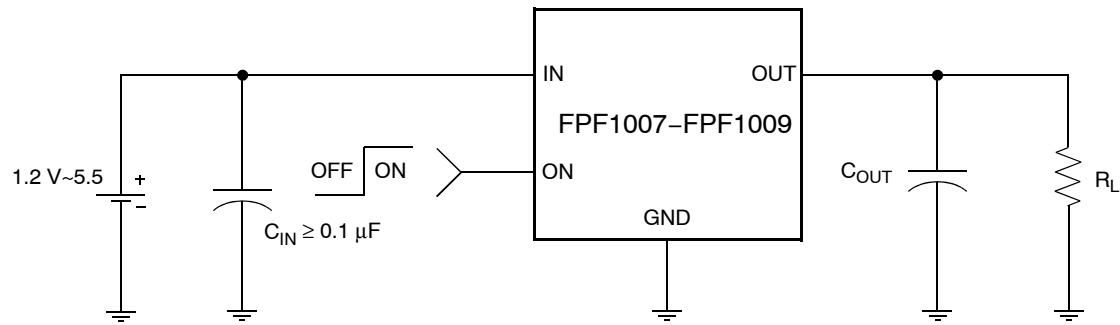


Figure 1. Typical Application Circuit

## Functional Block Diagram

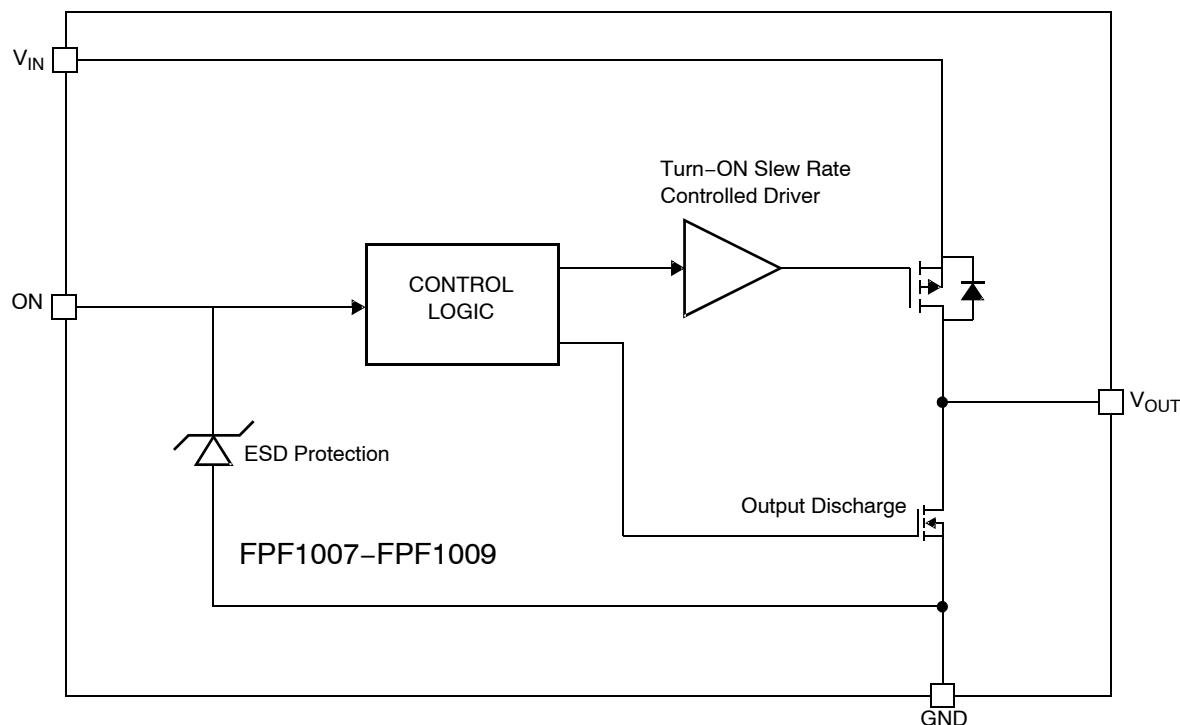
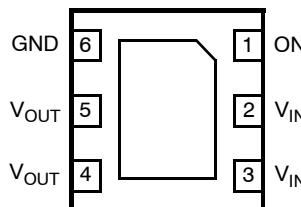


Figure 2. Functional Block Diagram

# FPF1007 – FPF1009

## Pin Configuration



(Bottom View)

**Figure 3. Pin Configuration**

## PIN DESCRIPTIONS

Name	Type	Description
4, 5	V <sub>OUT</sub>	Switch Output: Output of the power switch
2, 3	V <sub>IN</sub>	Supply Input: Input to the power switch and the supply voltage for the IC
6	GND	Ground
1	ON	ON/OFF Control Input

## ABSOLUTE MAXIMUM RATINGS

Parameter	Min	Max	Unit
V <sub>IN</sub> , V <sub>OUT</sub> , ON to GND	-0.3	6.0	V
Maximum Continuous Switch Current		1.5	A
Power Dissipation at T <sub>A</sub> = 25°C (Note 1)		1.2	W
Storage Junction Temperature	-65	150	°C
Operating Temperature Range	-40	85	°C
Thermal Resistance, Junction to Ambient		86	°C/W
Electrostatic Discharge Protection	HBM CDM	8000 2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Package power dissipation on 1 square inch pad, 2 oz. copper board.

## RECOMMENDED OPERATING RANGE

Symbol	Parameter	Min	Max	Unit
V <sub>IN</sub>	Input Voltage	1.2	5.5	V
T <sub>A</sub>	Ambient Operating Temperature	-40	85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# FPF1007 – FPF1009

## ELECTRICAL CHARACTERISTICS

$V_{IN}$  = 1.2 to 5.5 V,  $T_A$  = –40 to +85°C unless otherwise noted. Typical values are at  $V_{IN}$  = 3.3 V and  $T_A$  = 25°C.

Symbol	Parameter	Test Condition		Min	Typ	Max	Unit
<b>Basic Operation</b>							
$V_{IN}$	Operating Voltage			1.2		5.5	V
$I_Q$	Quiescent Current	$I_{OUT} = 0 \text{ mA}$ $V_{ON} = \text{Enabled}$	$V_{IN} = 3.3 \text{ V}$		8		$\mu\text{A}$
			$V_{IN} = 5.5 \text{ V}$			15	
$I_{Q(\text{off})}$	Off Supply Current	$V_{ON} = \text{GND}$ , $V_{OUT} = \text{OPEN}$			1		$\mu\text{A}$
$I_{SD(\text{off})}$	Off Switch Current	$V_{ON} = \text{GND}$ , $V_{OUT} = \text{GND}$			0.1	1.0	$\mu\text{A}$
$R_{ON}$	On-Resistance	$V_{IN} = 5.5 \text{ V}$ , $I_{OUT} = 200 \text{ mA}$ , $T_A = 25^\circ\text{C}$		30	40		$\text{m}\Omega$
		$V_{IN} = 3.3 \text{ V}$ , $I_{OUT} = 200 \text{ mA}$ , $T_A = 25^\circ\text{C}$		40	55		
		$V_{IN} = 1.5 \text{ V}$ , $I_{OUT} = 200 \text{ mA}$ , $T_A = 25^\circ\text{C}$		100	130		
		$V_{IN} = 1.2 \text{ V}$ , $I_{OUT} = 200 \text{ mA}$ , $T_A = 25^\circ\text{C}$		175	250		
		$V_{IN} = 3.3 \text{ V}$ , $I_{OUT} = 200 \text{ mA}$ , $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$	20		65		
$R_{PD}$	Output Pull Down Resistance	$V_{IN} = 3.3 \text{ V}$ , $V_{ON} = 0 \text{ V}$ , $T_A = 25^\circ\text{C}$		60			$\Omega$
$V_{IL}$	ON Input Logic Low Voltage	$V_{IN} = 1.2 \text{ V}$ to $5.5 \text{ V}$			0.4		V
$V_{IH}$	ON Input Logic High Voltage	$V_{IN} = 1.2 \text{ V}$ to $5.5 \text{ V}$		1			V
	ON Input Leakage (On)	$V_{ON} = V_{IN} = 5.5 \text{ V}$			10		$\mu\text{A}$
	ON Input Leakage (Off)	$V_{ON} = \text{GND}$			1		$\mu\text{A}$

## Dynamic

### FPF1007

$t_{ON}$	Turn On Time	$V_{IN} = 3.3 \text{ V}$ , $R_L = 500 \Omega$ , $R_{L\_CHIP} = 60 \Omega$ , $C_{OUT} = 0.1 \mu\text{F}$ , $T_A = 25^\circ\text{C}$		12		$\mu\text{s}$
$t_R$	Rise Time			10		$\mu\text{s}$
$t_{OFF}$	Turn Off Time			40		$\mu\text{s}$
$t_F$	Fall Time			15		$\mu\text{s}$

### FPF1008

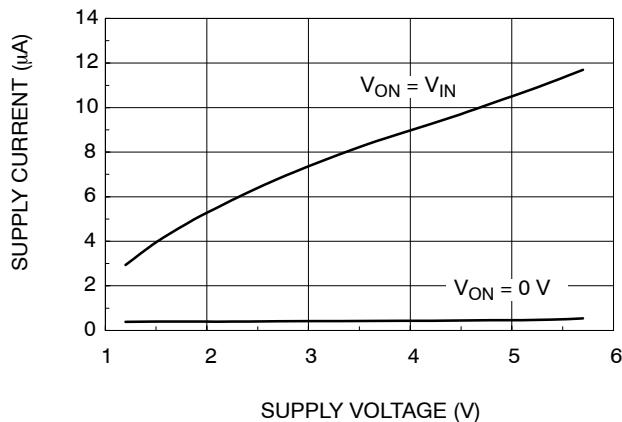
$t_{ON}$	Turn On Time	$V_{IN} = 3.3 \text{ V}$ , $R_L = 500 \Omega$ , $R_{L\_CHIP} = 60 \Omega$ , $C_{OUT} = 0.1 \mu\text{F}$ , $T_A = 25^\circ\text{C}$		125		$\mu\text{s}$
$t_R$	Rise Time			80		$\mu\text{s}$
$t_{OFF}$	Turn Off Time			40		$\mu\text{s}$
$t_F$	Fall Time			15		$\mu\text{s}$

### FPF1009

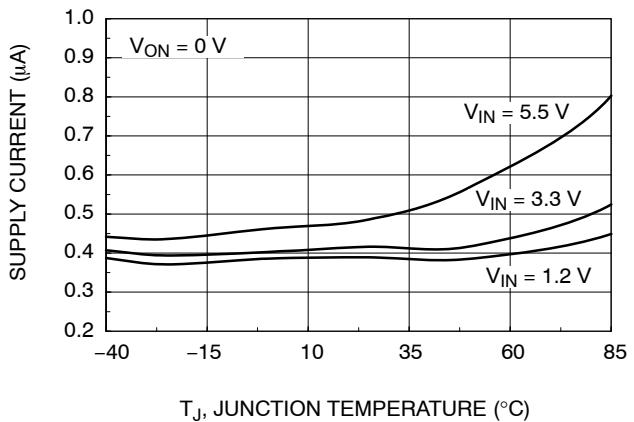
$t_{ON}$	Turn On Time	$V_{IN} = 3.3 \text{ V}$ , $R_L = 500 \Omega$ , $R_{L\_CHIP} = 60 \Omega$ , $C_{OUT} = 0.1 \mu\text{F}$ , $T_A = 25^\circ\text{C}$		2		ms
$t_R$	Rise Time			1		ms
$t_{OFF}$	Turn Off Time			40		$\mu\text{s}$
$t_F$	Fall Time			15		$\mu\text{s}$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

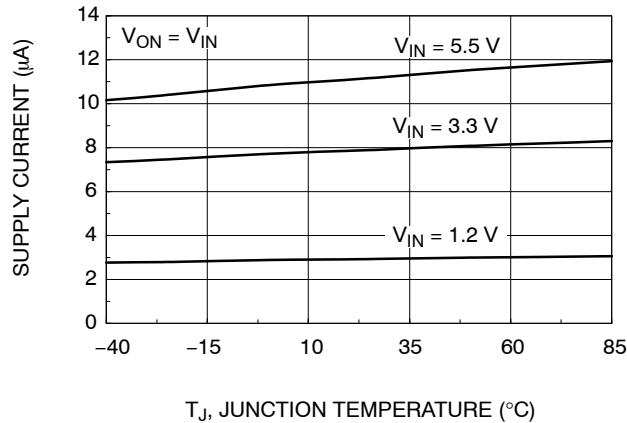
**TYPICAL CHARACTERISTICS**



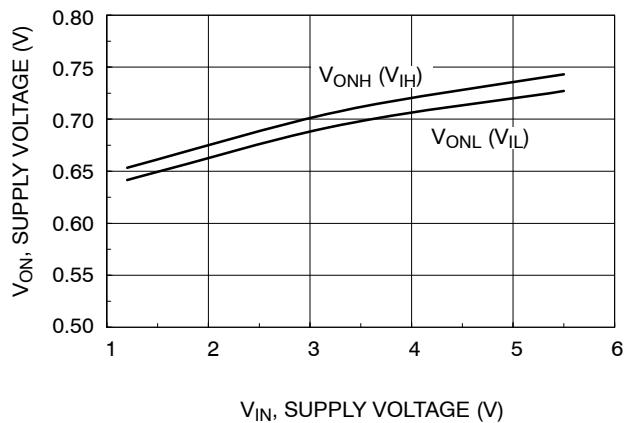
**Figure 4. Quiescent Current vs. Input Voltage**



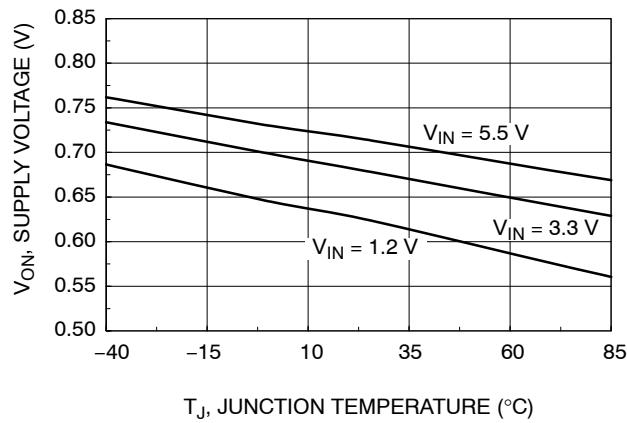
**Figure 5. Quiescent Current vs. Temperature**



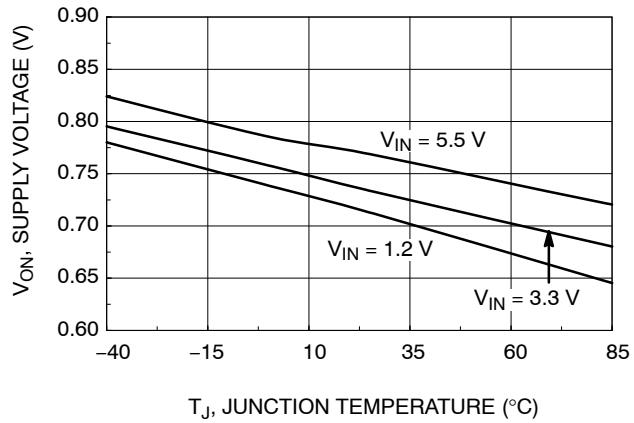
**Figure 6. Quiescent Current vs. Temperature**



**Figure 7.  $V_{ON}$  Voltage vs. Input Voltage**



**Figure 8.  $V_{ON}$  Low Voltage vs. Temperature**



**Figure 9.  $V_{ON}$  High Voltage vs. Temperature**

# FPF1007 – FPF1009

## TYPICAL CHARACTERISTICS (continued)

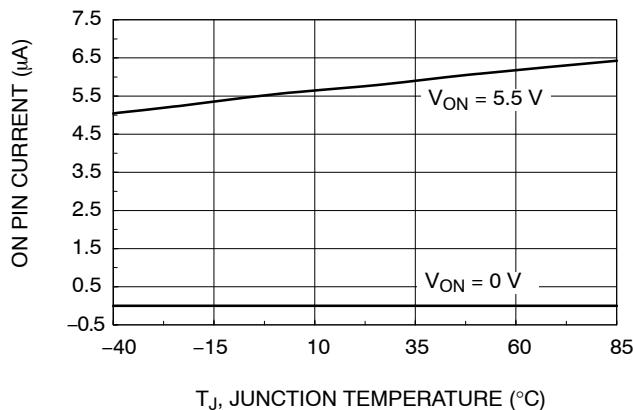


Figure 10. On Pin Current vs. Temperature

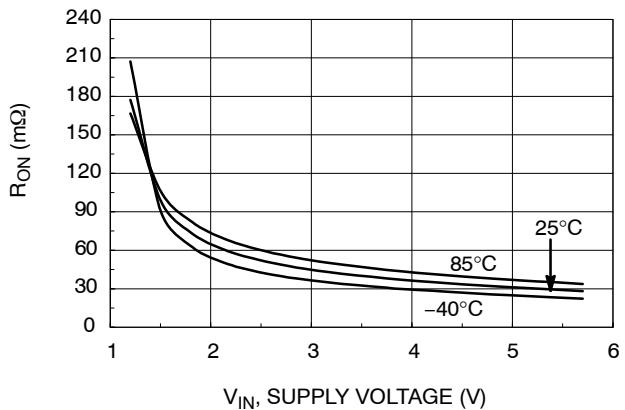


Figure 11. R<sub>ON</sub> vs. V<sub>IN</sub>

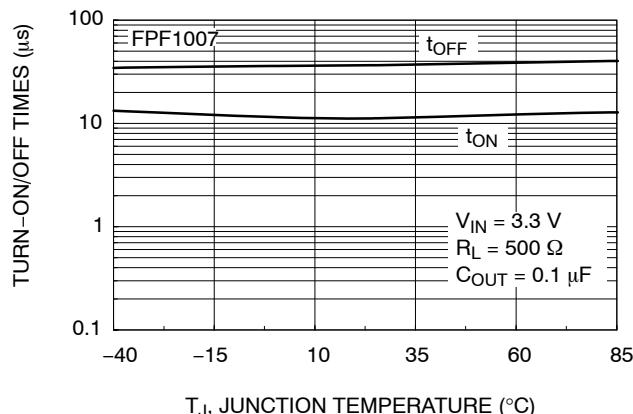


Figure 12. FPF1007 t<sub>ON</sub> / t<sub>OFF</sub> vs. Temperature

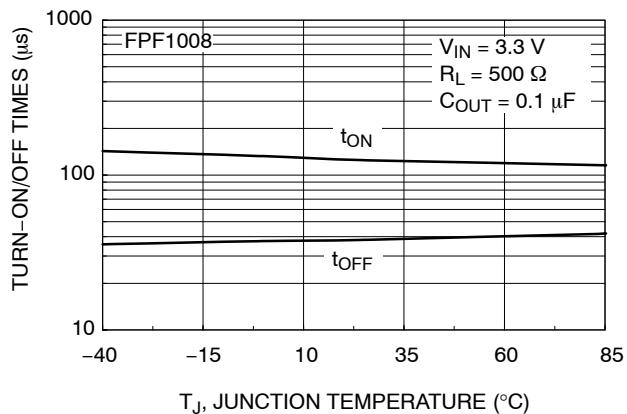


Figure 13. FPF1008 t<sub>ON</sub> / t<sub>OFF</sub> vs. Temperature

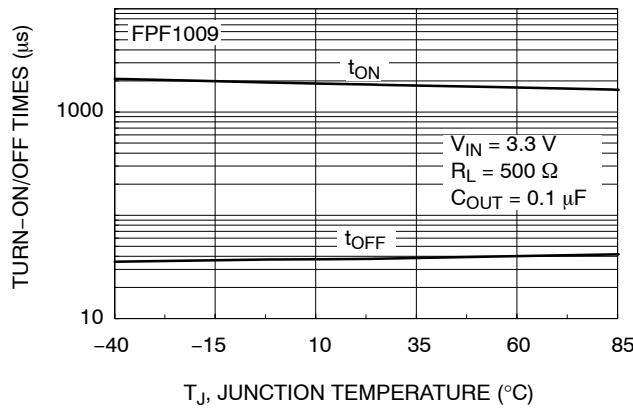


Figure 14. FPF1009 t<sub>ON</sub> / t<sub>OFF</sub> vs. Temperature

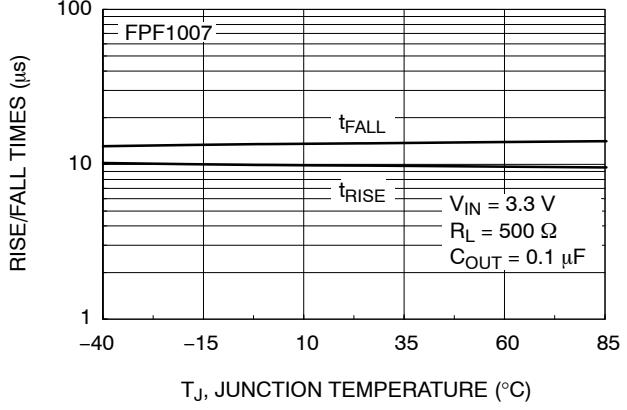
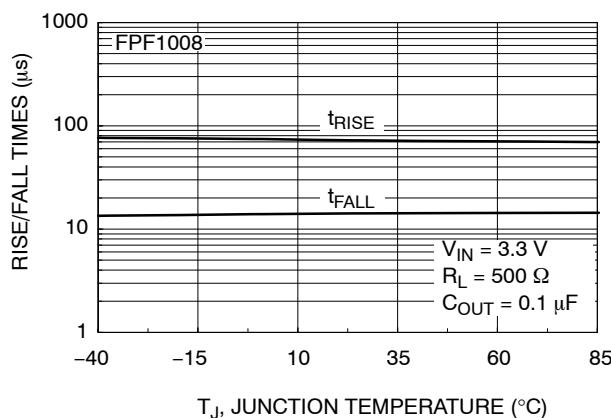
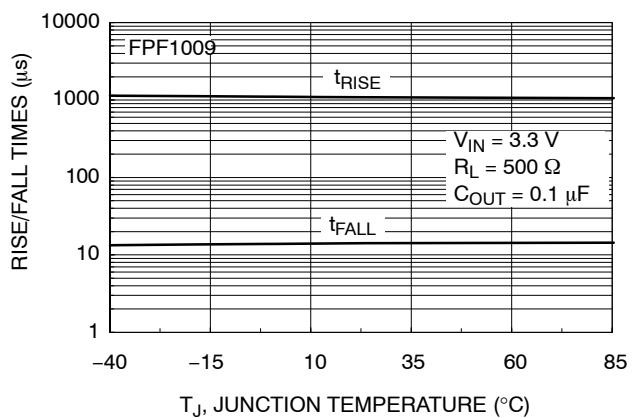


Figure 15. FPF1007 t<sub>RISE</sub> / t<sub>FALL</sub> vs. Temperature

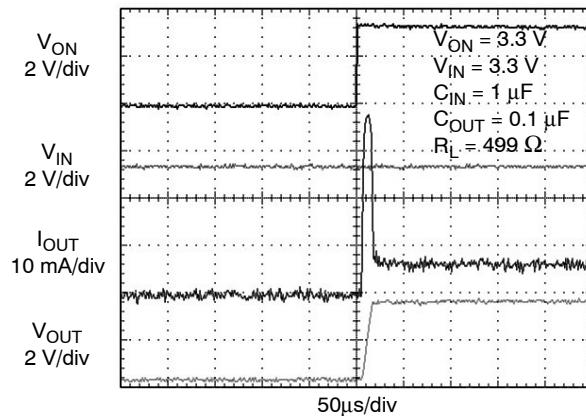
## TYPICAL CHARACTERISTICS (continued)



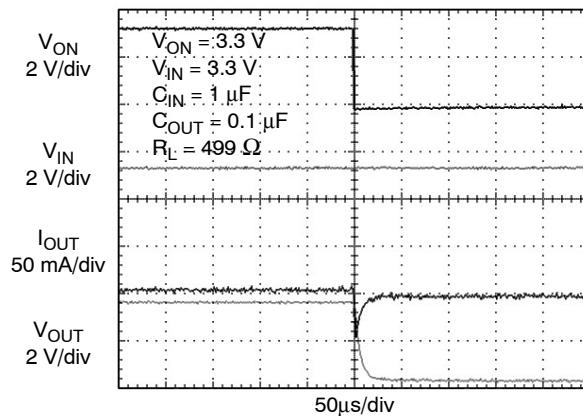
**Figure 16. FPF1008  $t_{RISE}$  /  $t_{FALL}$  vs. Temperature**



**Figure 17. FPF1009  $t_{RISE}$  /  $t_{FALL}$  vs. Temperature**

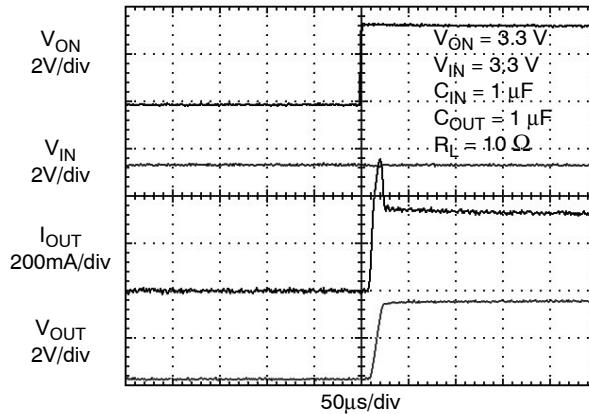


**Figure 18. FPF1007 Turn-On Response**

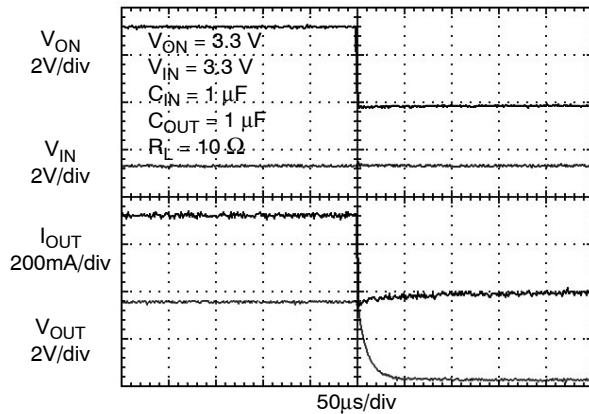


**Figure 19. FPF1007 Turn-Off Response**

Load current discharged through on-chip output discharge resistor



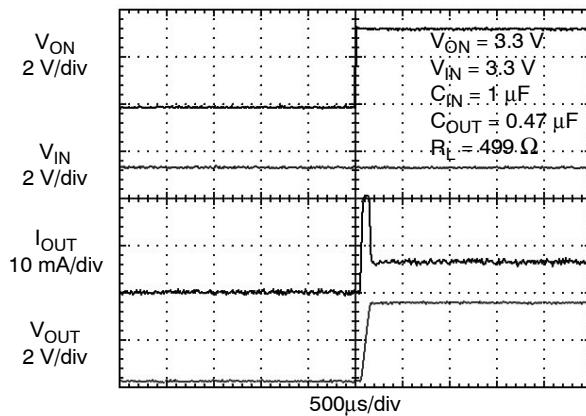
**Figure 20. FPF1007 Turn-On Response ( $C_{OUT} = 1\text{ }\mu\text{F}$ )**



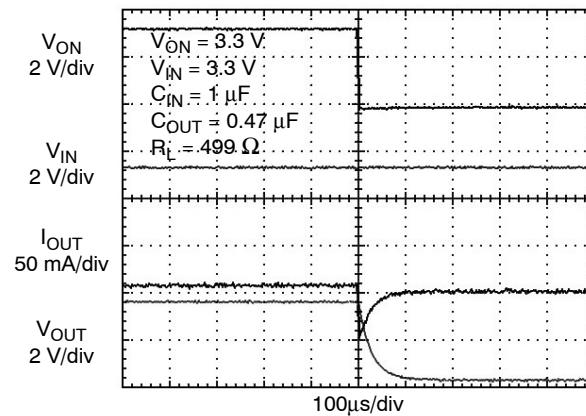
**Figure 21. FPF1007 Turn-Off Response**

# FPF1007 – FPF1009

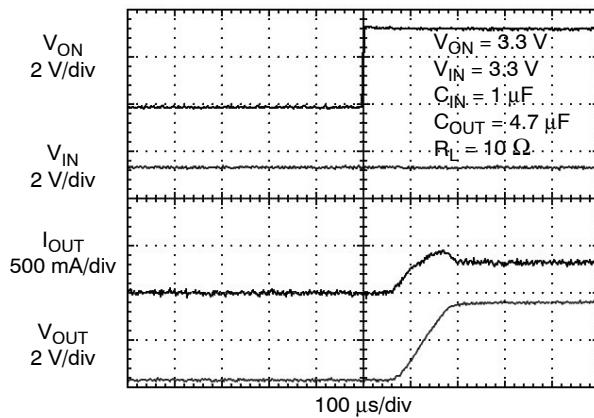
## TYPICAL CHARACTERISTICS (continued)



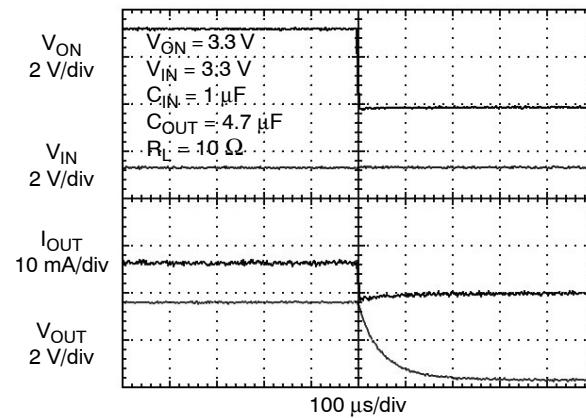
**Figure 22. FPF1008 Turn-On Response**



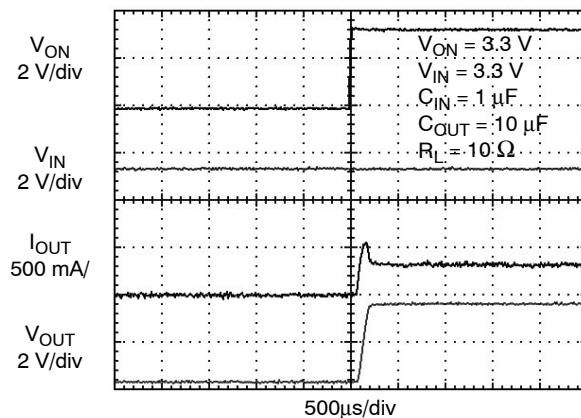
**Figure 23. FPF1008 Turn-Off Response**



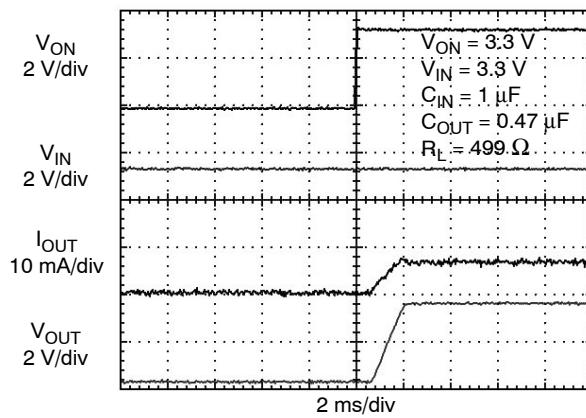
**Figure 24. FPF1008 Turn-On Response  
( $C_{OUT} = 4.7 \mu$ F)**



**Figure 25. FPF1008 Turn-Off Response**



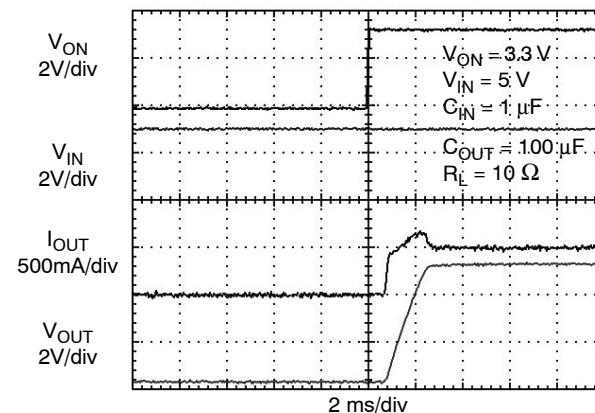
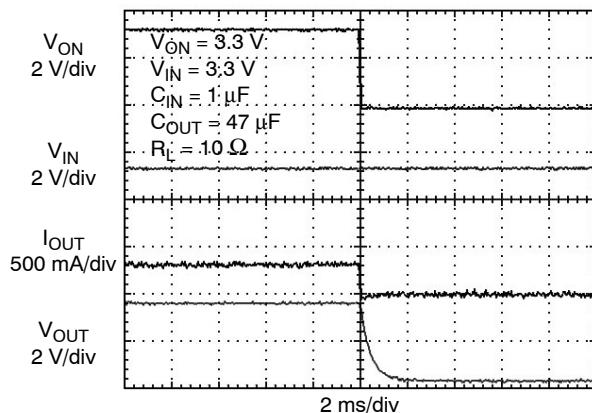
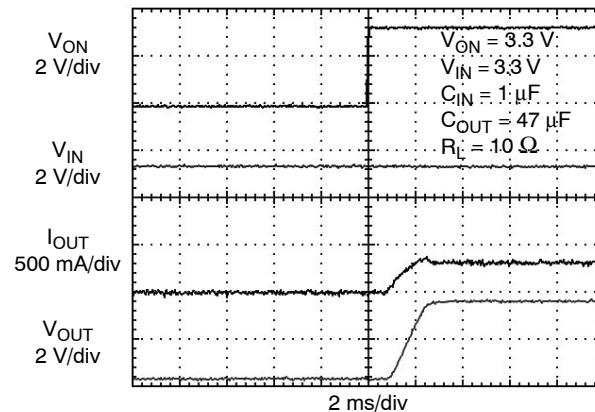
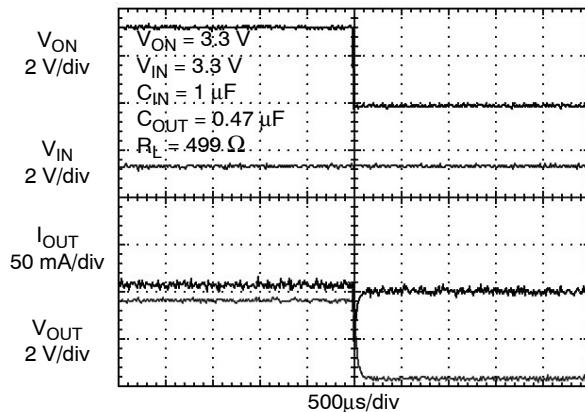
**Figure 26. FPF1008 Turn-On Response  
( $C_{OUT} = 10 \mu$ F)**



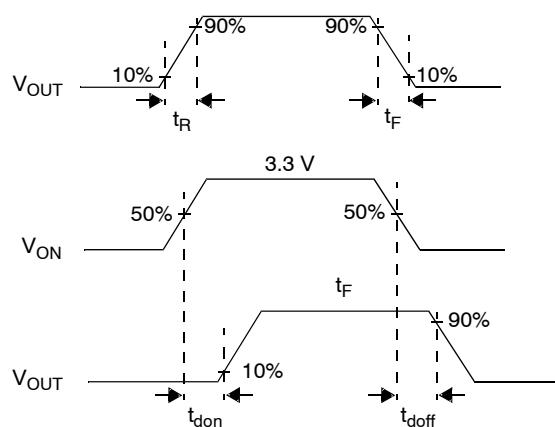
**Figure 27. FPF1009 Turn-On Response**

# FPF1007 – FPF1009

## TYPICAL CHARACTERISTICS (continued)



### Timing Diagram



**Figure 32. Timing Diagram**

where:

- $t_{ON}$  = Turn-On Time
- $t_{OFF}$  = Turn-Off Time
- $t_{don}$  = Turn-On Delay Time
- $t_{doff}$  = Turn-Off Delay Time
- $t_R$  = Rise Time
- $t_F$  = V<sub>OUT</sub> Fall Time
- $t_{ON} = t_R + t_{don}$
- $t_{OFF} = t_F + t_{doff}$

## FPF1007 – FPF1009

### ORDERING INFORMATION

Part Number	Switch R <sub>ON</sub> at 5.5 V (Typ.)	Rise Time (Typ.)	Output Discharge (Typ.)	ON Pin Activity	Top Mark	Shipping <sup>†</sup>
FPF1007	30 mΩ, PMOS	10 µs	60 Ω	Active HIGH	007	3000 / Tape & Reel
FPF1008	30 mΩ, PMOS	80 µs	60 Ω	Active HIGH	008	3000 / Tape & Reel
FPF1009	30 mΩ, PMOS	1 ms	60 Ω	Active HIGH	009	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

# MECHANICAL CASE OUTLINE

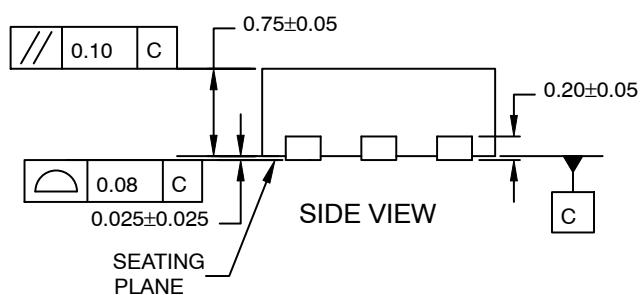
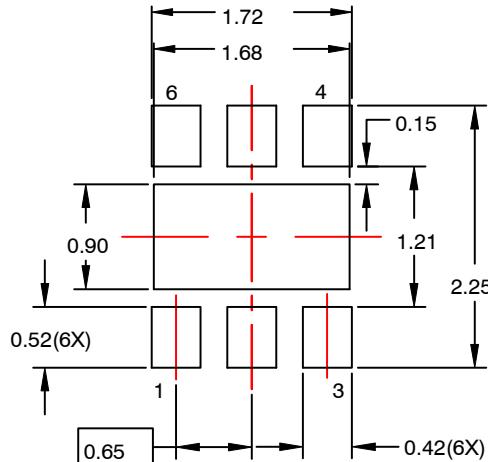
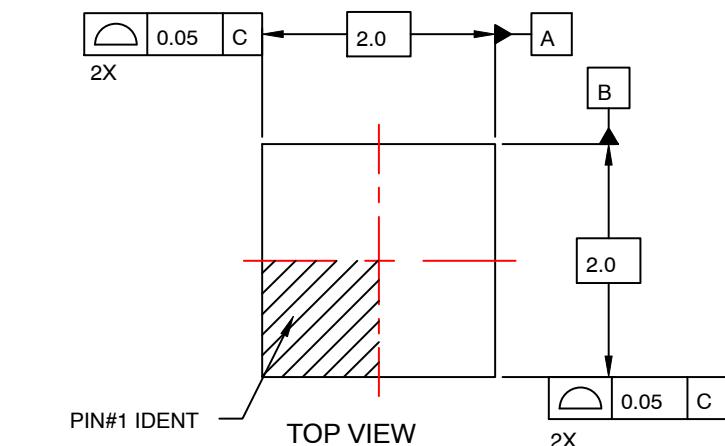
## PACKAGE DIMENSIONS

ON Semiconductor®

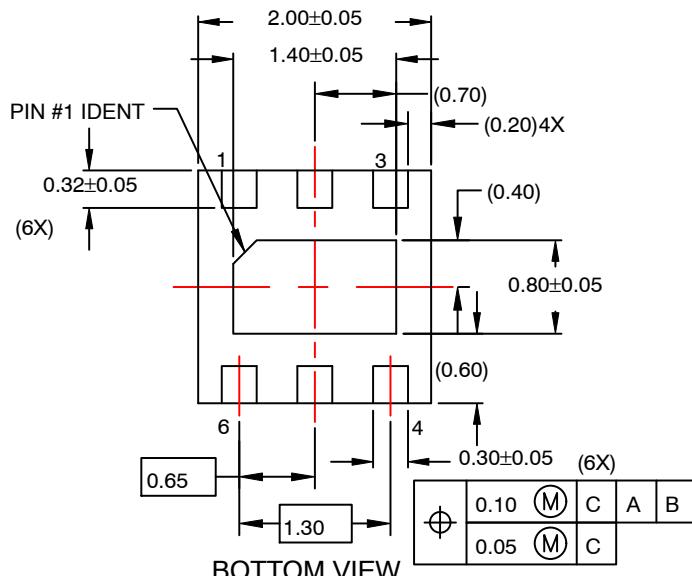


WDFN6 2x2, 0.65P  
CASE 511CY  
ISSUE O

DATE 31 JUL 2016



RECOMMENDED LAND PATTERN



NOTES:

- PACKAGE DOES NOT FULLY CONFORM TO JEDEC MO-229 REGISTRATION
- DIMENSIONS ARE IN MILLIMETERS.
- DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.

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